10V Drive Nch MOS FET

RDX060N60

●Structure

Silicon N-channel MOS FET

● Features

- 1) Low on-resistance.
- 2) Low input capacitance.
- 3) Excellent resistance to damage from static electricity.

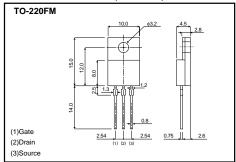
Applications

Switching

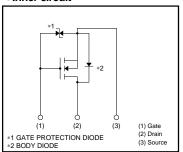
Packaging specifications

	Package	Bulk
Туре	Code	-
	Basic ordering unit (pieces)	500
RDX060N60		0

●External dimensions (Unit : mm)



●Inner circuit



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol		Limits	Unit	
Drain-source voltage		V _{DSS}		600	V	
Gate-source voltage		V _{GSS}		±30	V	
Dunin assument	Continuous	ΙD	*1	±6	Α	
Drain current	Pulsed	IDP	*2	±24	Α	
Source current (Body diode)	Continuous	Is		6	Α	
	Pulsed	I _{SP}	*2	24	Α	
Avalanche current		las	*3	6	Α	
Avalanche energy		Eas	*4	150	mJ	
Total power dissipation (Tc=25°C)		PD		40	W	
Channel temperature		Tch		150	°C	
Range of storage temperature		Tstg		-55 to +150	°C	

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to case	Rth(ch-c)	3.125	°C/W

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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	-	_	±10	μΑ	Vgs= ±25V, Vps=0V
Drain-source breakdown voltage	V _{(BR) DSS}	600	-	_	V	I _D = 1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	-	-	25	μΑ	V _{DS} = 600V, V _{GS} =0V
Gate threshold voltage	V _{GS (th)}	2.0	_	4.0	V	V _{DS} = 10V, I _D = 1mA
Static drain-source on-state resistance	RDS (on)*	-	0.9	1.2	Ω	In= 3.0A, Ves= 10V
Forward transfer admittance	Y _{fs} *	2.5	4.3	-	S	V _{DS} = 10V, I _D = 3.0A
Input capacitance	Ciss	-	950	_	pF	Vps= 25V
Output capacitance	Coss	-	110	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	-	20	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	-	20	_	ns	V _{DD} ≒ 150V
Rise time	tr *	_	14	_	ns	ID= 3.0A
Turn-off delay time	t _{d (off)} *	_	40	_	ns	V _{GS} = 10V R _L = 50Ω
Fall time	t _f *	-	28	_	ns	R _G =10Ω
Total gate charge	Qg *	-	25	_	nC	V _{DD} ≒300V
Gate-source charge	Q _{gs} *	-	6.5	-	nC	V _{GS} = 10V
Gate-drain charge	Q _{gd} *	_	12	_	nC	I _D = 6A

^{*}Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	_	_	1.5	V	I _S = 6A, V _{GS} =0V
Reverse recovery time	trr *	-	500	_	ns	I _{DR} = 6A, V _{GS} =0V
Reverse recovery charge	Qrr *	-	4.6	_	μC	di/dt= 100A / μs

^{*} Pulsed

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Appendix1-Rev1.1